

REVISIONS

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Add "Changes in accordance with NOR 5962-R115-92."	92-01-27	M. A. Frye
B	Add software data protection. Increase data retention to 20 years, minimum. Add device types 08 through 16. Remove tests t _{DHWL} , t _{WHDX} , and ESDS requirements from drawing.	93-07-21	M. A. Frye
C	Add "Changes in accordance with NOR 5962-R071-95."	95-02-14	M. A. Frye
D	Updated boilerplate paragraphs. ksr	05-04-15	Raymond Monnin
E	Updated body of drawing to reflect current requirements. – glg	11-12-16	Charles Saffle

The original first page has been replaced.

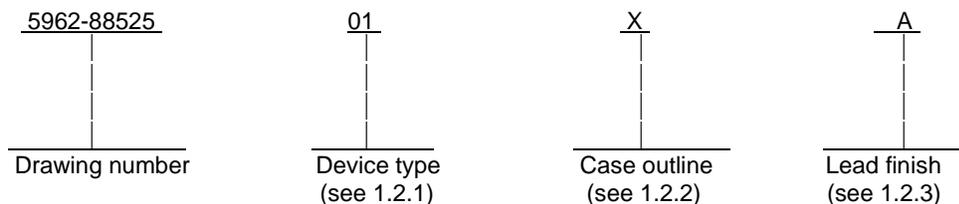
REV																				
SHEET																				
REV	E	E	E	E	E	E	E	E	E											
SHEET	15	16	17	18	19	20	21	22	23											
REV STATUS OF SHEETS	REV			E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	
	SHEET			1	2	3	4	5	6	7	8	9	10	11	12	13	14			

PMIC N/A	PREPARED BY Kenneth Rice	<p align="center">DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil</p>																	
<p align="center">STANDARD MICROCIRCUIT DRAWING</p> <p align="center">THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE</p> <p align="center">AMSC N/A</p>	CHECKED BY Raymond Monnin																		
	APPROVED BY Michael A. Frye	<p align="center">MICROCIRCUIT, MEMORY, DIGITAL, CMOS 32K X 8 EEPROM, MONOLITHIC SILICON</p>																	
	DRAWING APPROVAL DATE 88-08-29																		
	REVISION LEVEL E	<table border="1"> <tr> <td>SIZE A</td> <td>CAGE CODE 67268</td> <td rowspan="2">5962-88525</td> </tr> <tr> <td colspan="2">SHEET 1 OF 23</td> </tr> </table>	SIZE A	CAGE CODE 67268	5962-88525	SHEET 1 OF 23													
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1. SCOPE

1.1 Scope. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function	Access time	Write speed	Write mode	End of Write Indicator	polling	Endurance	Software data protect
01	See 6.6	(32K X 8 EEPROM)	350 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
02			300 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
03			250 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
04			200 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
05			250 ns	10 ms	byte/page	<u>DATA</u>	polling	100,000 cycles	No
06			150 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
07			150 ns	3 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	No
08			150 ns	10 ms	byte/page	<u>DATA</u>	polling	100,000 cycles	No
09			350 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
10			300 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
11			250 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
12			200 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
13			250 ns	10 ms	byte/page	<u>DATA</u>	polling	100,000 cycles	Yes
14			150 ns	10 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
15			150 ns	3 ms	byte/page	<u>DATA</u>	polling	10,000 cycles	Yes
16			150 ns	10 ms	byte/page	<u>DATA</u>	polling	100,000 cycles	Yes

1.2.2 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	Terminals	Package style
U	See figure 1	128	Grid array
X	GDIPI-T28 or CDIP2-T28	28	Dual-in-line
Y	CQCC1-N32	32	Rectangular leadless chip carrier
Z	CDFP4-F28	28	Flat package

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

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1.3 Absolute maximum ratings. 1/

Supply voltage range (V_{CC})	-0.3 V dc to +6.25 V dc
Storage temperature range	-65°C to +150°C
Maximum power dissipation (P_D).....	1.0 W
Lead temperature (soldering, 10 seconds).....	+300°C
Junction temperature (T_J) 2/.....	+175°C
Thermal resistance, junction-to-case (Θ_{JC})	See MIL-STD-1835
Input voltage range (V_{IL} , V_{IH})	-0.3 V dc to +6.25 V dc
Data retention.....	10 years (minimum)
Endurance: Types 01-04, 06, 07, 09-12, 14, 15	10,000 cycles/byte (minimum)
Types 05, 08, 13 ,16.....	100,000 cycles/byte (minimum)
Chip clear voltage (V_H)	15.0 V dc

1.4 Recommended operating conditions. 1/

Supply voltage range (V_{CC})	+4.5 V dc to +5.5 V dc
Case operating temperature range (T_C)	-55°C to +125°C
Input voltage, low range (V_{IL})	-0.1 V dc to +0.8 V dc
Input voltage, high range (V_{IH}).....	+2.0 V dc to V_{CC} +0.3 V dc

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <https://assist.daps.dla.mil/quicksearch/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.

1/ All voltages are referenced to V_{SS} (ground).
2/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.

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3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.2 herein and on figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Truth table(s). See 3.2.3.1 and 3.2.3.2

3.2.3.1 Unprogrammed or erased devices. The truth table for unprogrammed devices shall be as specified on figure 3.

3.2.3.2 Programmed devices. The requirements for supplying programmed devices are not part of this drawing.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 Marking. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.

3.5.1 Certification/compliance mark. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used.

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DLA Land and Maritime-VA shall be required for any change that affects this drawing.

3.9 Verification and review. DLA Land and Maritime, DLA Land and Maritime's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Processing EEPROMS. All testing requirements and quality assurance provisions herein shall be satisfied by the manufacturer prior to delivery.

3.10.1 Erasure of EEPROMS. When specified, devices shall be erased in accordance with the procedures and characteristics specified in 4.4.3.

3.10.2 Programmability of EEPROMS. When specified, devices shall be programmed to the specified pattern using the procedures and characteristics specified in 4.4.2. Software data protect procedures shall be as specified in 4.4.5.

3.10.3 Verification of erasure or programmability of EPROMS. When specified, devices shall be verified as either programmed to the specified pattern or erased. As a minimum, verification shall consist of reading the device per the procedures and characteristics specified in 4.4.4. Any bit that does not verify to be in the proper state shall constitute a device failure, and shall be removed from the lot.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V, 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified <u>1/</u>	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Supply current (active)	I _{CC1}	$\overline{CE} = \overline{OE} = V_{IL}$, $\overline{WE} = V_{IH}$ all I/O's = 0 mA, Inputs = V _{CC} = 5.5 V, f = 1/tAVAV (minimum)	1,2,3	All		80	mA
Supply current (TTL standby)	I _{CC2}	$\overline{CE} = V_{IH}$, $\overline{OE} = V_{IL}$ all I/O's = 0 mA Inputs = V _{CC} - 0.3 V	1,2,3	All		3	mA
Supply current (CMOS standby)	I _{CC3}	$\overline{CE} = V_{CC} - 0.3 V$ all I/O's = 0 mA, Inputs = V _{IL} to V _{CC} - 0.3 V	1,2,3	All		350	μA
Input leakage (high)	I _{IH}	V _{IN} = 5.5 V	1,2,3	All	-10	10	μA
Input leakage (low)	I _{IL}	V _{IN} = 0.1 V	1,2,3	All	-10	10	μA
Output leakage (high)	I _{OZH} <u>2/</u>	V _{OUT} = 5.5 V, $\overline{CE} = V_{IH}$	1,2,3	All	-10	10	μA
Output leakage (low)	I _{OLZ} <u>2/</u>	V _{OUT} = 0.1 V, $\overline{CE} = V_{IH}$	1,2,3	All	-10	10	μA
Input voltage low	V _{IL}		1,2,3	All	-0.1	0.8	V
Input voltage high	V _{IH}		1,2,3	All	2.0	V _{CC} + 0.3V	V
Output voltage low	V _{OL}	I _{OL} = 2.1 mA, V _{IH} = 2.0 V V _{CC} = 4.5 V, V _{IL} = 0.8 V	1,2,3	All		0.45	V
Output voltage high	V _{OH}	I _{OH} = -400 μA, V _{IH} = 2.0 V V _{CC} = 4.5 V, V _{IL} = 0.8 V	1,2,3	All	2.4		V
\overline{OE} high leakage (chip erase)	I _{OE}	V _H = 13 V	1,2,3	All	-10	100	μA

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V, 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified 1/	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Input capacitance	C _I 3/ 4/	V _{IN} = 0 V, V _{CC} = 5.0 V T _A = +25°C, f = 1 MHz See 4.3.1c	4	All		10	pF
Output capacitance	C _O 3/ 4/	V _{OUT} = 0 V, V _{CC} = 5.0 V T _A = +25°C, f = 1 MHz See 4.3.1c	4	All		10	pF
Read cycle time	t _{AVAV} 5/	See figure 4	9,10,11	01,09	350	ns	
				02,10	300		
				03,05,11,13	250		
				04,12	200		
				06-08,14-16	150		
Address access time	t _{AVQV} 5/		9,10,11	01,09	350	ns	
				02,10	300		
				03,05,11,13	250		
				04,12	200		
				06-08,14-16	150		
Chip enable access time	t _{ELQV} 5/		9,10,11	01,09	350	ns	
				02,10	300		
				03,05,11,13	250		
				04,12	200		
				06-08,14-16	150		
Output enable access time	t _{OLQV} 5/		9,10,11	01-03,05	100	ns	
				09-11,13			
				04,06,07,08 12,14,15,16			80
Chip enable to output in low Z	t _{ELQX} 4/ 5/		9,10,11	All	10	ns	
Chip disable to output in high Z	t _{EHQZ} 4/ 5/		9,10,11	01,02,09,10	80	ns	
				03-08,11-16	60		
Output enable to output in low Z	t _{OLQX} 4/ 5/		9,10,11	All	10	ns	
Output disable to output in high Z	t _{OHQZ} 4/ 5/		9,10,11	01,02,09,10	80	ns	
				03-08,11-16	60		
Output hold from address change	t _{AXQX} 4/ 5/		9,10,11	All	0	ns	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V, 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified 1/	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Write cycle time	t _{WHWL1} t _{EHHL1} 5/	See figure 5 or 7 as applicable	9,10,11	01-06, 08-14, 16 07,15		10	ms
Address set-up time	t _{AVEL} 5/ t _{AVWL}				20		
Address hold time	t _{ELAX} 5/ t _{WLAX}	See figures 5, 6, or 7 as applicable	9,10,11	All	150		ns
Write set-up time	t _{WLEL} 5/ t _{ELWL}				0		
Write hold time	t _{EHWH} 5/ t _{WHEH}	See figures 5, 6, or 7 as applicable	9,10,11	All	0		ns
$\overline{\text{OE}}$ set-up time	t _{OHHL} t _{OHWL} 5/				20		
$\overline{\text{OE}}$ hold time	t _{EHOL} t _{WHOL} 5/	See figures 5, 6, or 7 as applicable	9,10,11	All	20		ns
$\overline{\text{WE}}$ pulse width	t _{ELEH} t _{WLWH} 5/ 6/				.150	1	
Data set-up time	t _{DVEH} t _{DVWH} 5/	See figures 5, 6, or 7 as applicable	9,10,11	All	50		ns
Delay to next write	t _{DVWL} 4/ t _{DVEL} 5/					10	
Data hold time	t _{EHDX} t _{WHDX} 5/	See figure 5 or 7 as applicable	9,10,11	All	10		ns
Byte load cycle	t _{WHWL2} 5/ 6/				.20	149	

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C V _{SS} = 0 V, 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified <u>1/</u>	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Last byte loaded to data polling	t _{WHEL} t _{EHEL} <u>5/</u>	See figure 5 or 6 as applicable	9,10,11	All		650	μs
$\overline{\text{CE}}$ setup time	t _{ELWL} <u>5/</u>	See figure 8	9,10,11	All	5		μs
Output set-up time	<u>5/</u> t _{OVHWL}		9,10,11	All	5		μs
$\overline{\text{CE}}$ hold time	t _{WHEH} <u>5/</u>		9,10,11	All	5		μs
$\overline{\text{OE}}$ hold time	<u>5/</u> t _{WHOH}		9,10,11	All	5		μs
High voltage	V _H <u>5/</u>		9,10,11	All	12	13	V
Chip erase	<u>5/</u> t _{WLWH2}		9,10,11	All		210	ms
$\overline{\text{WE}}$ pulse width for chip erase	t _{WLWH1} <u>5/</u>		9,10,11	All	10		ms

1/ DC and read mode.

2/ Connect all address inputs and $\overline{\text{OE}}$ to V_{IH} and measure I_{OLZ} and I_{OHZ} with the output under test connected to V_{OUT}.

3/ All pins not being tested are to be open.

4/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.

5/ Tested by application of specified timing signals and conditions, including:

Equivalent ac test conditions:

Devices: All.

Output load: 1 TTL gate and C_L = 100 pF (minimum) or equivalent circuit.

Input rise and fall times ≤ 10 ns.

Input pulse levels: 0.4 V and 2.4 V.

Timing measurements reference levels:

Inputs: 1 V and 2 V.

Outputs: 0.8 V and 2 V.

6/ During a page write operation the cycle time defined by t_{WLWH} and t_{WHWL2} shall not be less than 1 μs.

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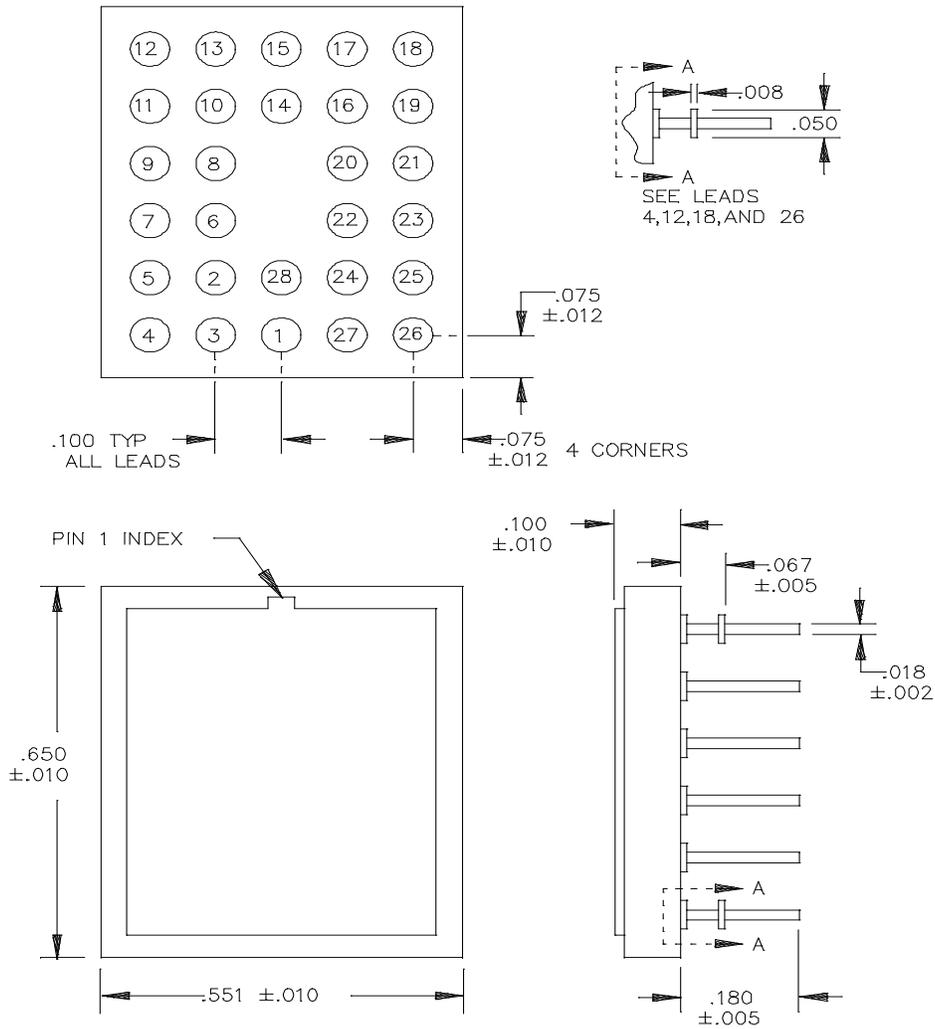
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- NOTES:
1. Dimensions are in inches.
 2. Metric equivalents are given for general information only.

Inches	mm
.002	0.05
.005	0.13
.008	0.20
.010	0.25
.012	0.30
.050	1.27
.067	1.70
.075	1.90
.100	2.54
.180	4.57
.551	14.00
.650	16.51

FIGURE 1. Case outline.

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Device types	All	
Case outlines	U, X, Z	Y
Terminal numbers	Terminal symbols	
1	A ₁₄	NC
2	A ₁₂	A ₁₄
3	A ₇	A ₁₂
4	A ₆	A ₇
5	A ₅	A ₆
6	A ₄	A ₅
7	A ₃	A ₄
8	A ₂	A ₃
9	A ₁	A ₂
10	A ₀	A ₁
11	I/O ₀	A ₀
12	I/O ₁	NC
13	I/O ₂	I/O ₀
14	V _{SS}	I/O ₁
15	I/O ₃	I/O ₂
16	I/O ₄	V _{SS}
17	I/O ₅	NC
18	I/O ₆	I/O ₃
19	I/O ₇	I/O ₄
20	$\overline{\text{CE}}$	I/O ₅
21	A ₁₀	I/O ₆
22	$\overline{\text{OE}}$	I/O ₇
23	A ₁₁	$\overline{\text{CE}}$
24	A ₉	A ₁₀
25	A ₈	$\overline{\text{OE}}$
26	A ₁₃	NC
27	$\overline{\text{WE}}$	A ₁₁
28	V _{CC}	A ₉
29	---	A ₈
30	---	A ₁₃
31	---	$\overline{\text{WE}}$
32	---	V _{CC}

FIGURE 2. Terminal connections.

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Mode	\overline{CE}	\overline{OE}	\overline{WE}	I/O	Device type
Read	V_{IL}	V_{IL}	V_{IH}	D_{OUT}	All
Standby	V_{IH}	X	X	High Z	
Chip clear	V_{IL}	V_H	V_{IL}	$D_{IN} = V_{IH}$	
Byte write	V_{IL}	V_{IH}	V_{IL}	Data in	
Write inhibit	X	V_{IL}	X	High Z/D out	
Write inhibit	X	X	V_{IH}	High Z/D out	

X = Don't care state.

FIGURE3. Truth table for unprogrammed devices.

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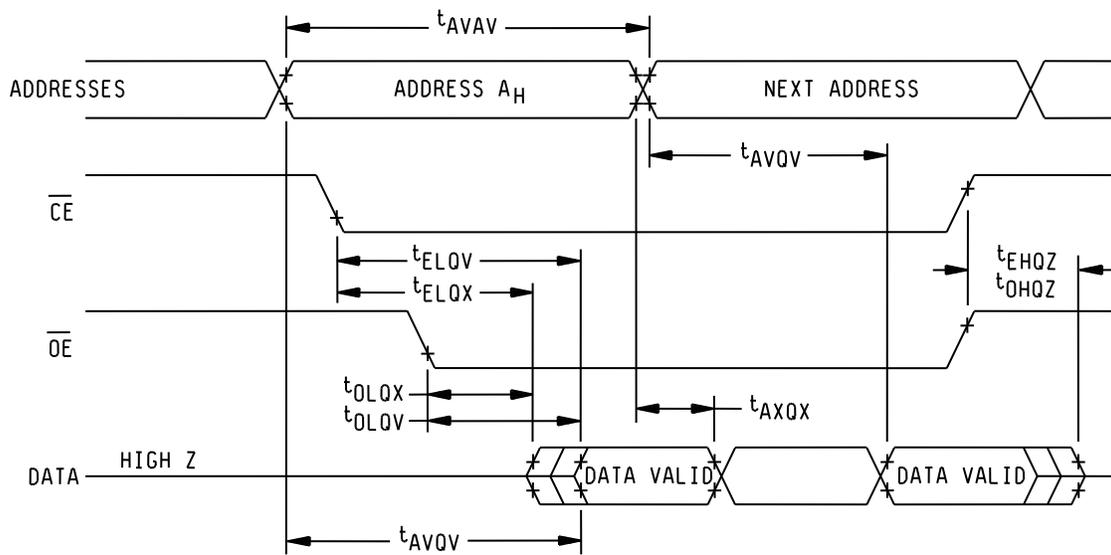


FIGURE 4. Timing waveforms.

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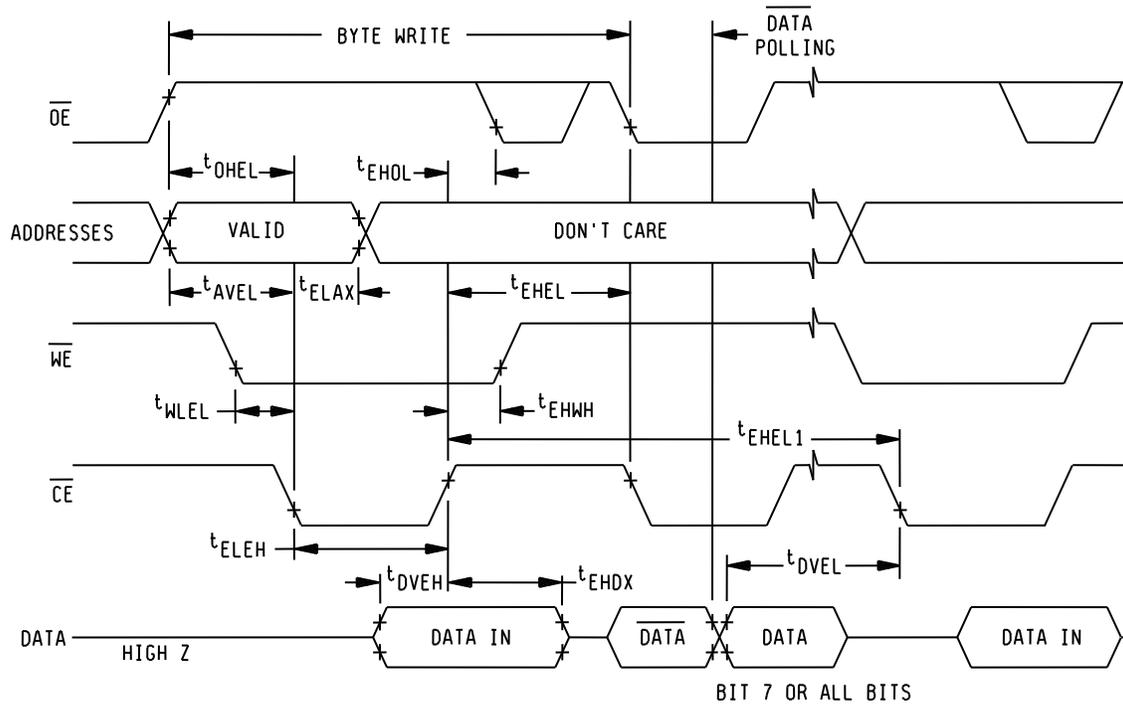


FIGURE 5. \overline{CE} controlled byte write programming waveform.

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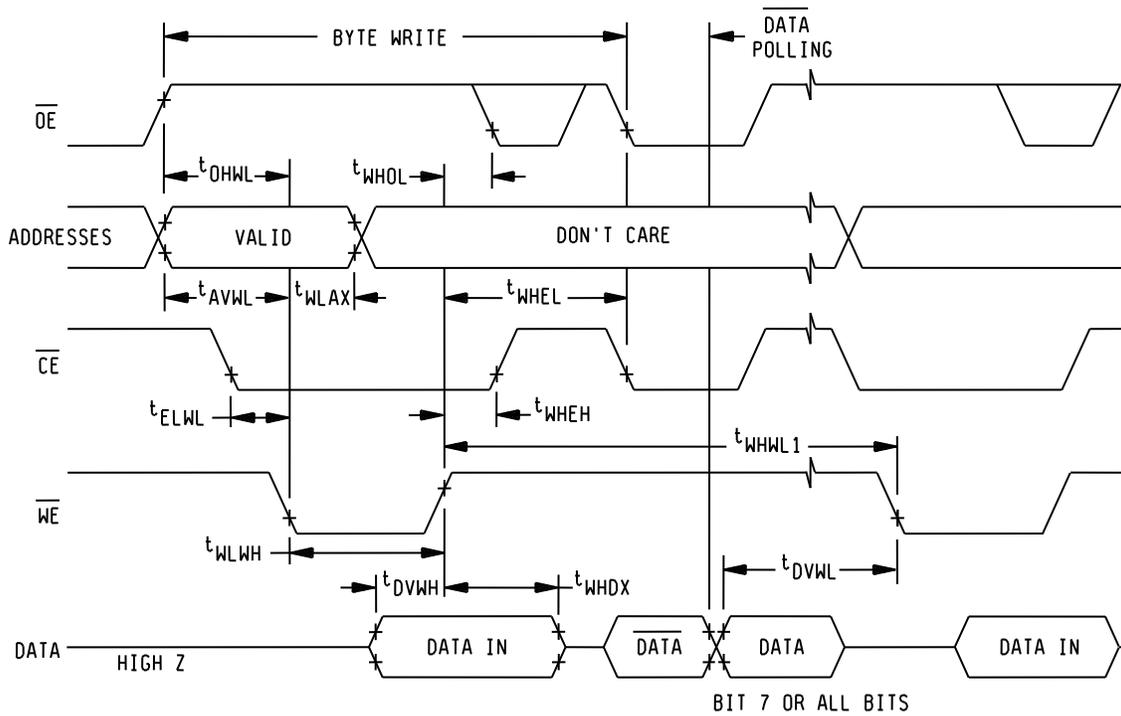


FIGURE 6. \overline{WE} controlled byte write programming waveform.

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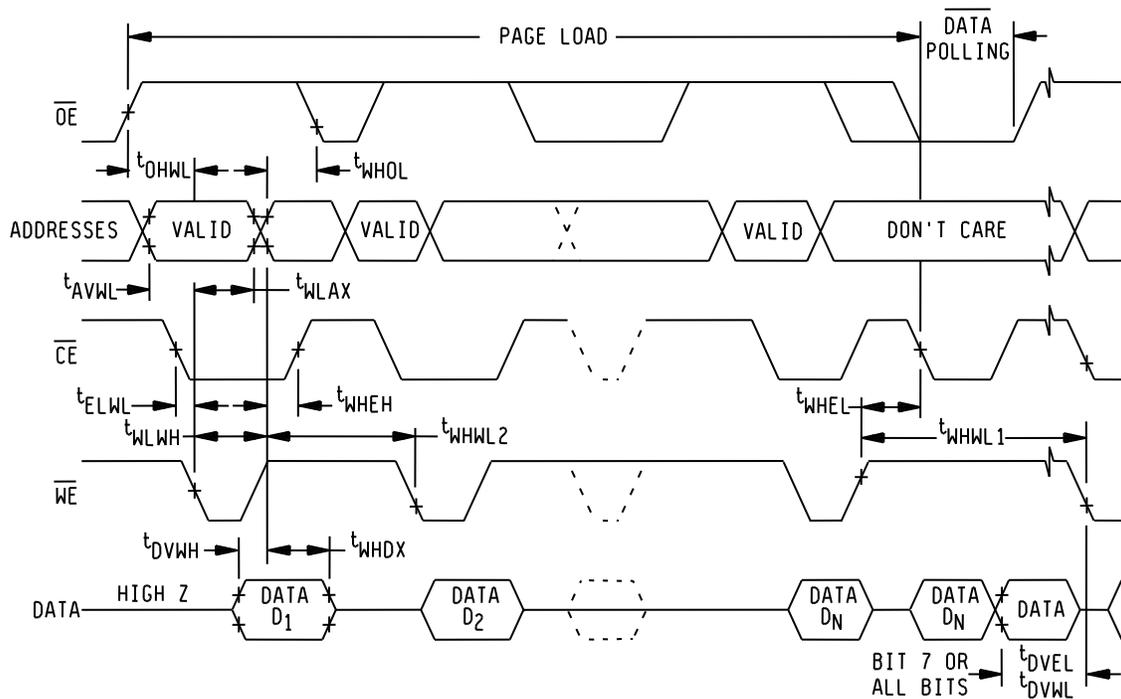
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Note: The page write operation of the device allows 2 to 64 bytes of data to be loaded into the device and then simultaneously written during the internal programming period.

FIGURE 7. Page write programming waveform.

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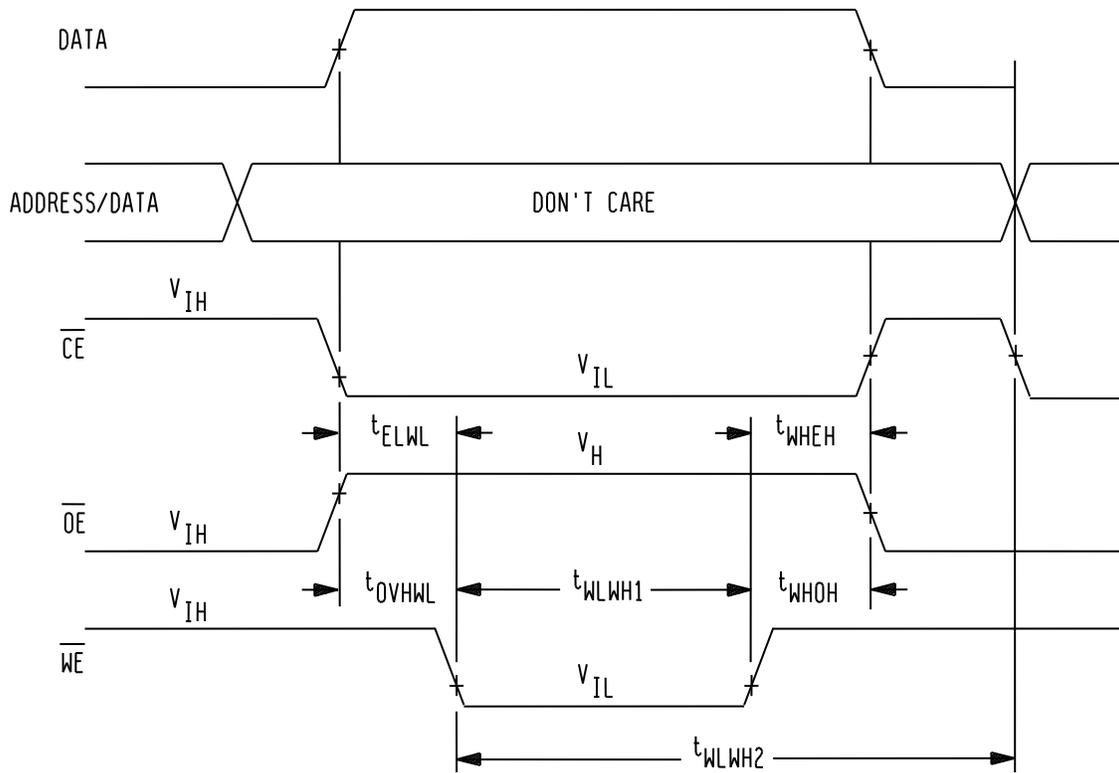
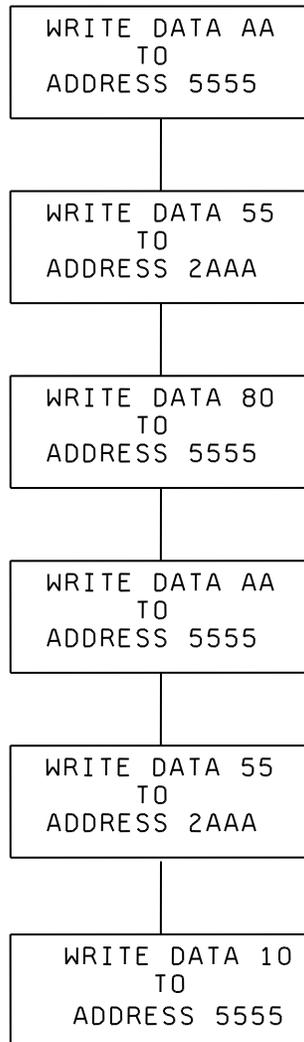


FIGURE 8. Timer chip clear waveform.

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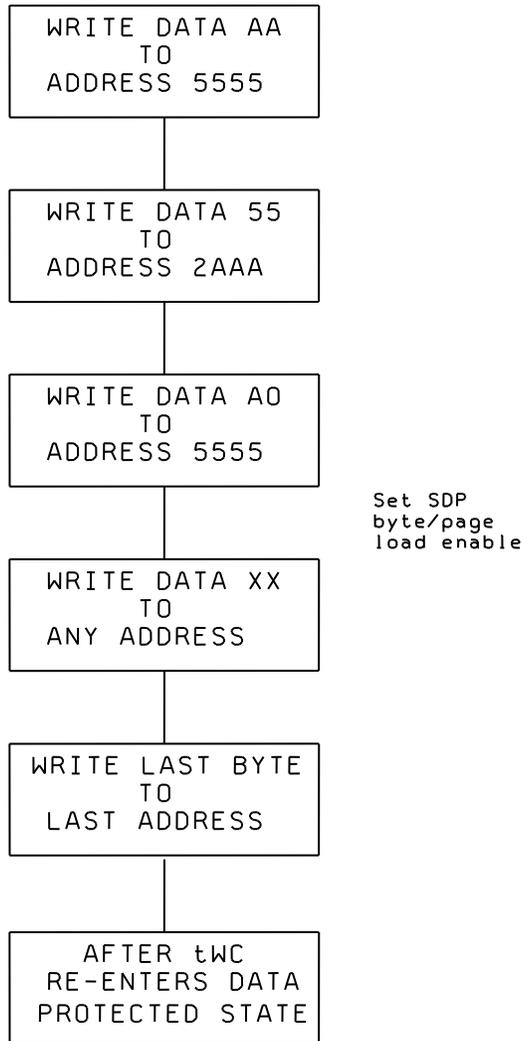


NOTES:

1. Software chip clear timings are referenced to \overline{WE} or \overline{CE} inputs, whichever is last to go low, and the \overline{WE} or \overline{CE} inputs, whichever is first to go high.
2. The command sequence must conform to the page write timing.

FIGURE 9. Software chip clear algorithm (device types 09-16).

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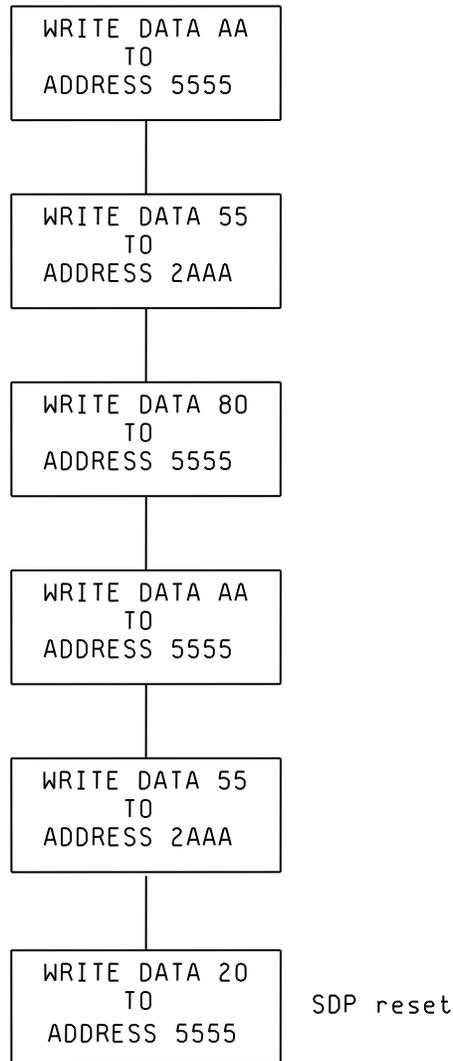


NOTES:

1. Software data protection timings are referenced to the \overline{WE} or \overline{CE} inputs, whichever is last to go low, and the \overline{WE} or \overline{CE} inputs, whichever is first to go high.
2. The command sequence and subsequent data must conform to page write timing.

FIGURE 10. Set software data protect algorithm (device types 09-16).

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NOTES:

1. Reset software data protection timings are referenced to the \overline{WE} or \overline{CE} inputs, whichever is last to go low, and the \overline{WE} or \overline{CE} inputs, whichever is first to go high.
2. The command sequence and subsequent data must conform to page write timing.

FIGURE 11. Reset software data protect algorithm(device types 09-16).

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4. VERIFICATION

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

- (1) Test condition D or F. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- (2) T_A = +125°C, minimum.
- (3) Devices shall be burned-in containing a checkerboard pattern or equivalent.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

c. An endurance/data retention test prior to burn-in, in accordance with method 1033 of MIL-STD-883, shall be included as part of the screening procedure with the following conditions:

- (1) Cycling may be block, byte, or page at equipment room ambient temperature and shall cycle all bytes for a minimum of 10,000 cycles for devices 01-04, 06,07, 09-12, 14,15 and a minimum of 50,000 cycles for device 05,08,13, and 16.
- (2) After cycling, perform a high temperature unbiased bake for 72 hours at +150°C (minimum). The storage time may be accelerated by using higher temperature in accordance with the Arrhenius Relationship:

$$A_F = e^{-\frac{E_A}{K} \left[\frac{1}{T_1} - \frac{1}{T_2} \right]}$$

A_F = acceleration factor (unitless quantity) = t₁ / t₂

T = temperature in Kelvin (i.e., t₁+ 273)

t₁ = time (hrs) at temperature T₁

t₂ = time (hrs) at temperature T₂

K = Boltzmanns constant = 8.62 x 10⁻⁵ eV/°K using an apparent activation energy (E_A) of 0.6 eV.

The maximum storage temperature shall not exceed +200°C for packaged devices or +300°C for unassembled devices.

- (3) Read the data retention pattern and test using subgroups 1, 7, and 9 (minimum, e.g., high temperature equivalent subgroups 2, 8A, and 10 may be used) after cycling and bake, prior to burn-in. Devices having bits not in the proper state after storage shall constitute a device failure.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_I and C_O measurement) shall be measured only for the initial test and after process or design changes which may affect input or output capacitance.

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d. Subgroups 7 and 8 shall include verification of the truth table.

4.3.2 Group C inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. All devices requiring end-point electrical testing shall be programmed with a checkerboard or equivalent alternating bit pattern.
- c. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition D or F. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
 - (2) $T_A = +125^\circ\text{C}$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- d. An endurance test, in accordance with method 1033 of MIL-STD-883, shall be added to group C inspection prior to performing the steady-state life test (see 4.3.2c) and extended data retention (see 4.3.2e).

Cycling may be block, byte, or page from devices passing group A after the completion of the requirements of 4.2 herein. Initially, two groups of devices shall be formed, cell 1 and cell 2.

The following conditions shall be met:

- (1) Cell 1 shall be cycled at -55°C and cell 2 shall be cycled at $+125^\circ\text{C}$ for a minimum of 10,000 cycles for device types 01-04,06,07,09-12,14,15 and 100,000 cycles for device types 05,08,13, and 16.
 - (2) Perform group A subgroups 1, 7, and 9 after cycling. Form two new cells (cells 3 and 4) for steady-state life and extended data retention. Cell 3 for steady-state life test consists of one-half of the devices from cell 1 and one-half of the devices from cell 2. Cell 4 for extended data retention consists of the remaining devices from cells 1 and 2.
 - (3) The sample plans for cell 1, cell 2, cell 3, and cell 4 shall individually be the same as for group C, as specified in method 5005 of MIL-STD-883.
- e. Extended data retention shall consist of:
- (1) All devices shall be programmed with a charge on all memory cells in each device, such that the cell will read opposite the state that the cell would read in its equilibrium state (e.g., worst case pattern, see 4.2a(3)).
 - (2) Unbiased bake for 1000 hours (minimum) at $+150^\circ\text{C}$ (minimum). The unbiased bake time may be accelerated by using higher temperature in accordance with the Arrhenius Relationship:

$$A_F = e^{-\frac{E_A}{K} \left[\frac{1}{T_1} - \frac{1}{T_2} \right]}$$

A_F = acceleration factor (unitless quantity) = t_1 / t_2

T = temperature in Kelvin (i.e., $t_1 + 273$)

t_1 = time (hrs) at temperature T_1

t_2 = time (hrs) at temperature T_2

K = Boltzmanns constant = $8.62 \times 10^{-5} \text{eV}/^\circ\text{K}$ using an apparent activation energy (E_A) of 0.6 eV.

The maximum storage temperature shall not exceed $+200^\circ\text{C}$ for packaged devices or $+300^\circ\text{C}$ for unassembled devices.

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(3) Read the pattern after bake and perform endpoint electrical tests for table II herein for group C.

4.3.3 Groups D inspections. Group D inspection shall be in accordance with table IV of method 5005 of MIL-STD-883 and as follows:

- a. End-point electrical parameters shall be as specified in table II herein.
- b. All devices requiring end-point electrical testing shall be programmed with a checkerboard or equivalent alternating bit pattern.

TABLE II. Electrical test requirements. 1/ 2/ 3/ 4/ 5/

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	1, 7, 9 or 2, 8A, 10
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 8, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4**, 7, 8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3, 7, 8, 9, 10, 11

1/ (*) Indicates PDA applies to subgroups 1 and 7.

2/ Any or all subgroups may be combined when using multifunction testers.

3/ Subgroup 7 and 8 shall consist of writing and reading the data pattern specified in accordance with the limits of table I subgroups 9, 10, and 11.

4/ For all electrical tests, the device shall be programmed to the data pattern specified.

5/ (**) Indicates that subgroup 4 will only be performed during initial qualification and after design or process changes (see 4.3.1c).

4.4 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables of method 5005 of MIL-STD-883 and as follows.

4.4.1 Voltage and current. All voltages given are referenced to the microcircuit V_{SS} terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

4.4.2 Programming procedure. The following procedure shall be followed when programming (Write) is performed. The waveforms and timing relationships shown on figure 5 (in accordance with appropriate device type) and the conditions specified in table I shall be adhered to. Information is introduced by selectively programming a TTL low or TTL high on each I/O of the address desired. Functionality shall be verified at all temperatures (group A subgroups 7 and 8) by programming all bytes of each device and verifying the pattern used.

4.4.3 Erasing procedure. There are two forms of erasure, chip and byte, whereby all bits or the address selected will be erased to a TTL high.

- a. Chip erase is performed in accordance with the waveforms and timing relationships shown on figure 8 (in accordance with appropriate device type) and the conditions specified in table I.

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b. Byte erase is performed in accordance with the waveforms and timing relationships shown on figures 5, 6, and 7 (in accordance with appropriate device type) and the conditions specified in table I.

4.4.4 Read mode operation. The waveforms and timing relationships shown on figure 4 and the conditions specified in table I shall be applied when reading the device. Pattern verification utilizes the read mode.

4.4.5 Software data protection. Device types 09-16 software data protection offers a method of preventing inadvertent writes (see figure 9). The instructions, waveforms, and timing relationships shown on figures 4, 5, 6, 7, 10, and 11, and the conditions specified in table I shall apply (see 3.10.2).

4.4.5.1 Set software data protection. Device types 09-16 are placed in protected state by writing a series of instructions (see figure 10) to the device. Once protected, writing to the device may only be performed by executing the same sequence of instructions appended with either a byte write operation or page write operation. The waveforms and timing relationships shown on figures 5, 6, and 7 and the test conditions and limits specified in table I shall apply.

4.4.5.2 Reset software data protection. Device types 09-16 protection feature is reset by writing a series of instructions (see figure 11) to the device. The waveforms and timing relationships shown on figures 5, 6, and 7 and the test conditions and limits specified in table I shall apply.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 Record of users. Military and industrial users shall inform DLA Land and Maritime when a system application requires configuration control and the applicable SMD. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-0547.

6.5 Comments. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DLA Land and Maritime-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 11-12-16

Approved sources of supply for SMD 5962-88525 are listed below for immediate acquisition only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8852501XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-35DM/883 DM28C256-350/B X28C256DMB-35
5962-8852501YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-35LM/883 LM28C256-350/B X28C256EMB-35
5962-8852501ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-35FM/883 FM28C256-350/B X28C256FMB-35
5962-8852501UA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-35UM/883 TM28C256-350/B X28C256KMB-35
5962-8852502XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-30DM/883 DM28C256-300/B X28C256DMB-30
5962-8852502YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-30LM/883 LM28C256-300/B X28C256EMB-30
5962-8852502ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-30FM/883 FM28C256-300/B X28C256FMB-30
5962-8852502UA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-30UM/883 TM28C256-300/B X28C256KMB-30
5962-8852503XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-25DM/883 DM28C256-250/B X28C256DMB-25

See notes at end of table.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8852503YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-25LM/883 LM28C256-250/B X28C256EMB-25
5962-8852503ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-25FM/883 FM28C256-250/B X28C256FMB-25
5962-8852503UA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-25UM/883 TM28C256-250/B X28C256KMB-25
5962-8852504XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-20DM/883 DM28C256-200/B X28C256DMB-20
5962-8852504YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-20LM/883 LM28C256-200/B X28C256EMB-20
5962-8852504ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-20FM/883 FM28C256-200/B X28C256FMB-20
5962-8852504UA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-20UM/883 TM28C256-200/B X28C256KMB-20
5962-8852505XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-25DM/883 DM28C256-250/B X28C256DMB-25
5962-8852505YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-25LM/883 LM28C256-250/B X28C256EMB-25
5962-8852505ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-25FM/883 FM28C256-250/B X28C256FMB-25
5962-8852505UA	0HSW3	AT28C256E-25UM/883
5962-8852506XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-15DM/883 DM28C256A-150/B X28C256DMB-15

See notes at end of table.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8852506YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-15LM/883 LM28C256A-150/B X28C256EMB-15
5962-8852506ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-15FM/883 FM28C256A-150/B X28C256FMB-15
5962-8852506UA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256-15UM/883 TM28C256A-150/B X28C256KMB-15
5962-8852507XA	0HSW3 <u>3</u> /	AT28C256F-15DM/883 DM28C256AH-150/B
5962-8852507YA	0HSW3 <u>3</u> /	AT28C256F-15LM/883 LM28C256AH-150/B
5962-8852507ZA	0HSW3 <u>3</u> /	AT28C256F-15FM/883 FM28C256AH-150/B
5962-8852507UA	0HSW3 <u>3</u> /	AT28C256F-15UM/883 TM28C256AH-150/B
5962-8852508XA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-15DM/883 DM55C256A-150/B X28C256DMB-15
5962-8852508YA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-15LM/883 LM55C256A-150/B X28C256EMB-15
5962-8852508ZA	0HSW3 <u>3</u> / <u>3</u> /	AT28C256E-15FM/883 FM55C256A-150/B X28C256FMB-15
5962-8852508UA	0HSW3	AT28C256E-15UM/883
5962-8852509XA	0HSW3 <u>3</u> /	AT28C256-35DM/883 X28C256DMB-35
5962-8852509YA	0HSW3 <u>3</u> /	AT28C256F-35LM/883 X28C256EMB-35
5962-8852509ZA	0HSW3 <u>3</u> /	AT28C256F-35FM/883 X28C256FMB-35

See notes at end of table.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8852509UA	0HSW3 <u>3</u> /	AT28C256F-35UM/883 X28C256KMB-35
5962-8852510XA	0HSW3 <u>3</u> /	AT28C256-30DM/883 X28C256DMB-30
5962-8852510YA	0HSW3 <u>3</u> /	AT28C256-30LM/883 X28C256EMB-30
5962-8852510ZA	0HSW3 <u>3</u> /	AT28C256-30FM/883 X28C256FMB-30
5962-8852510UA	0HSW3 <u>3</u> /	AT28C256-30UM/883 X28C256KMB-30
5962-8852511XA	0HSW3 <u>3</u> /	AT28C256-25DM/883 X28C256DMB-25
5962-8852511YA	0HSW3 <u>3</u> /	AT28C256-25LM/883 X28C256EMB-25
5962-8852511ZA	0HSW3 <u>3</u> /	AT28C256-25FM/883 X28C256FMB-25
5962-8852511UA	0HSW3 <u>3</u> /	AT28C256-25UM/883 X28C256KMB-25
5962-8852512XA	0HSW3 <u>3</u> /	AT28C256-20DM/883 X28C256DMB-20
5962-8852512YA	0HSW3 <u>3</u> /	AT28C256-20LM/883 X28C256EMB-20
5962-8852512ZA	0HSW3 <u>3</u> /	AT28C256-20FM/883 X28C256FMB-20
5962-8852512UA	0HSW3 <u>3</u> /	AT28C256-20UM/883 X28C256KMB-20
5962-8852513XA	0HSW3 <u>3</u> /	AT28C256E-25DM/883 X28C256DMB-25
5962-8852513YA	0HSW3 <u>3</u> /	AT28C256E-25LM/883 X28C256EMB-25
5962-8852513ZA	0HSW3 <u>3</u> /	AT28C256E-25FM/883 X28C256FMB-25

See notes at end of table.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number <u>3/</u>	Vendor similar PIN <u>2/</u>
5962-8852513UA	0HSW3 <u>3/</u>	AT28C256E-25UM/883 X28C256KMB-25
5962-8852514XA	0HSW3 <u>3/</u>	AT28C256-15DM/883 X28C256DMB-15
5962-8852514YA	0HSW3 <u>3/</u>	AT28C256-15LM/883 X28C256EMB-15
5962-8852514ZA	0HSW3 <u>3/</u>	AT28C256-15FM/883 X28C256FMB-15
5962-8852514UA	0HSW3 <u>3/</u>	AT28C256-15UM/883 X28C256KMB-15
5962-8852515XA	0HSW3	AT28C256F-15DM/883
5962-8852515YA	0HSW3	AT28C256F-15LM/883
5962-8852515ZA	0HSW3	AT28C256F-15FM/883
5962-8852515UA	0HSW3	AT28C256-15UM/883
5962-8852516XA	0HSW3 <u>3/</u>	AT28C256E-15DM/883 X28C256DMB-15
5962-8852516YA	0HSW3 <u>3/</u>	AT28C256E-15LM/883 X28C256EMB-15
5962-8852516ZA	0HSW3 <u>3/</u>	AT28C256E-15FM/883 X28C256FMB-15
5962-8852516UA	0HSW3	AT28C256E-15UM/883

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source.

Vendor CAGE
number

0HSW3

Vendor name
and address

ATMEL Corporation
1150 East Cheyenne Mountain Blvd.
Colorado Springs, CO 80906

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